

General Description

The MAX9491 multipurpose clock generator is ideal for communication applications. It offers a factory-programmable PLL output that can be set to almost any frequency, ranging from 4MHz to 200MHz. The MAX9491 uses a one-time-programmable (OTP) ROM to program the PLL output. The MAX9491 also features an integrated voltage-controlled crystal oscillator (VCXO) that is tuned by a DC voltage. The VCXO output is used as the PLL input. The VCXO has a wide ±200ppm (typ) tuning range. The OTP on the MAX9491 is factory preset, based upon the customer request. Contact the factory for samples with preferred frequencies.

The device operates from a 3.3V supply and is specified over the -40°C to +85°C extended temperature range. The MAX9491 is available in 14-pin TSSOP and 20-pin TQFN (5mm x 5mm) packages.

Applications

Telecommunications Data Networking Systems Home Entertainment Centers SOHO

Features

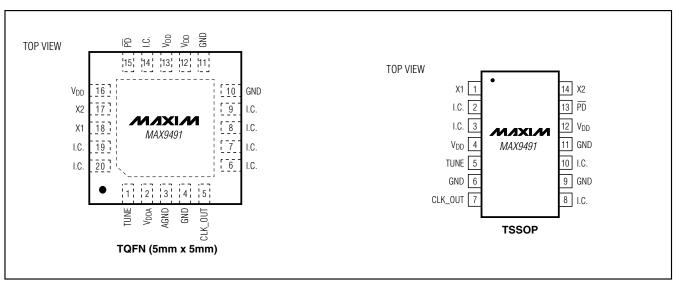
- ◆ 5MHz to 35MHz for Crystal-Clock Reference
- ♦ 5MHz to 50MHz for a Driver Clock Reference
- ♦ One Fractional-N PLL with Buffered Output
- ♦ 4MHz to 200MHz Output Frequency Range
- ♦ Low RMS Jitter PLL (< 13ps) at 197 MHz
- ♦ Integrated VCXO with ±200ppm Tuning Range
- Available in 14-Pin TSSOP and 20-Pin TQFN **Packages**
- ♦ +3.3V Supply
- ♦ -40°C to +85°C Temperature Range

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	PKG CODE
MAX9491ETP	-40°C to +85°C	20 TQFN-EP**	T2055-5
MAX9491EUD*	-40°C to +85°C	14 TSSOP	U14-2

^{*}Future product—contact factory for availability.

Pin Configurations



^{**}EP = Exposed pad.

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	0.3V to +4.0V
VDDA to AGND	0.3V to +4.0V
All Other Pins to GND	0.3V to $V_{DD} + 0.3V$
Short-Circuit Duration	
(all LVCMOS outputs)	Continuous
ESD Protection (Human Body Model)	±2kV

Continuous Power Dissipation ($T_A = +70$	O°C)
20-Lead TQFN (derate 21.3mW/°C at	
14-Pin TSSOP (derate 9.1mW/°C abo	ve +70°C)796.8mW
Storage Temperature Range	65°C to +150°C
Maximum Junction Temperature	+150°C
Operating Temperature Range	40°C to +85°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{DD} = V_{DDA} = +3.0V \text{ to } +3.6V \text{ and } T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}.$ Typical values at $V_{DD} = V_{DDA} = 3.3V$, $T_A = +25^{\circ}\text{C}$, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
LVCMOS INPUTS (PD, X1 as a re	ference INPL	JT CLK)					
Input High Level	VIH		2.0		V_{DD}	V	
Input Low Level	V _{IL}		0		0.8	V	
High-Level Input Current	lін	$V_{IN} = V_{DD}$			20	μΑ	
Low-Level Input Current	Ι _Ι L	V _{IN} = 0 -20				μΑ	
CLOCK OUTPUT (CLK_OUT)							
Output High Level	VoH	I _{OH} = -4mA	V _{DD} - 0.6			V	
Output Low Level	V _{OL}	I _{OL} = 4mA			0.4	V	
POWER SUPPLIES							
Digital Power-Supply Voltage	V_{DD}		3.0		3.6	V	
Analog Power-Supply Voltage	V_{DDA}		3.0		3.6	V	
Total Current for Digital and Analog Supplies	IDC	$f_{OUT} = 45MHz$, no load $f_{IN} = 13MHz$		10		mA	
Power-Down Current	I _{DC} 2	$\overline{PD} = low$	60			μΑ	

AC ELECTRICAL CHARACTERISTICS

 $(V_{DD} = V_{DDA} = +3.0V \text{ to } +3.6V, C_L = 10 \text{pF} \text{ and } T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}.$ Typical values are at $V_{DD} = V_{DDA} = 3.3V, T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 2)$

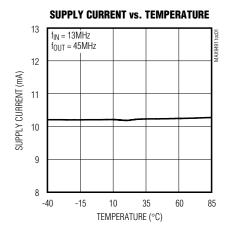
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT CLOCK (CLK_OUT)						
Minimum Frequency Range	four	f _{IN} = 5MHz to 50MHz	4			MHz
Maximum Frequency Range	fout	C _L < 5pF	133	200		IVI□Z
Clock Rise Time	t _R	20% to 80% of V _{DD} , f _{OUT} = 80MHz, f _{IN} = 13MHz		1.5		ns
Clock Fall Time	t _F	80% to 20% of V _{DD} , f _{OUT} = 80MHz, f _{IN} = 13MHz		1.3		ns
Duty Cycle		f _{OUT} = 45MHz, f _{IN} = 13MHz	44	50	56	%
		$f_{OUT} = 45MHz$, $f_{IN} = 13MHz$		14		
Output Period Jitter	JP	f _{OUT} = 80MHz, f _{IN} = 13MHz		22		ps RMS
		$f_{OUT} = 197MHz$, $f_{IN} = 13MHz$		13		
Soft Power-On Time	tPO2	\overline{PD} from low to high, f _{OUT} = 45MHz, f _{IN} = 13MHz, see Figure 2	1			ms
Hard Power-On Time	t _{PO1}	See Figure 2		15		ms
VCXO CLOCK						
Crystal Frequency	fXTL			27		MHz
Crystal Accuracy				±30		ppm
Tuning Voltage Range	VTUNE		0		3	V
VCXO Tuning Range		$V_{TUNE} = 0 \text{ to } 3V, C_1 = C_2 = 4pF$	±150	±200		ppm
TUNE Input Impedance	Z _{TUNE}			95		kΩ
Output CLK Accuracy		$V_{TUNE} = 1.5V, C_1 = C_2 = 4pF$		±50	•	ppm

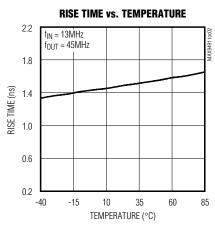
Note 1: All parameters are tested at $T_A = +25$ °C. Specifications over temperature are guaranteed by design and characterization.

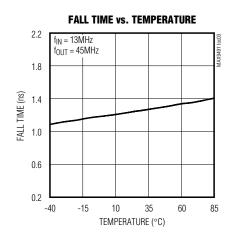
Note 2: Guaranteed by design and characterization; limits are set at ±6 sigma.

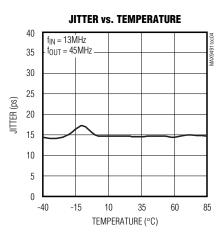
Typical Operating Characteristics

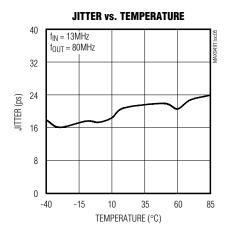
 $(V_{DD} = V_{DDA} = +3.3V, T_{A} = +25^{\circ}C, f_{IN} = 13MHz clock, C_{L} = 10pF, 27MHz, unless otherwise noted.)$

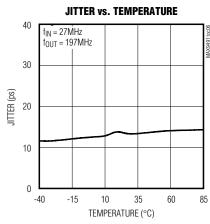


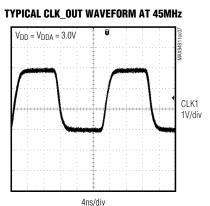


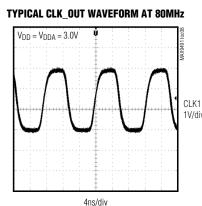


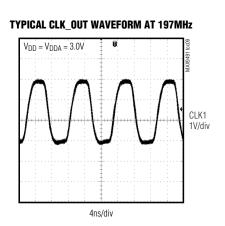






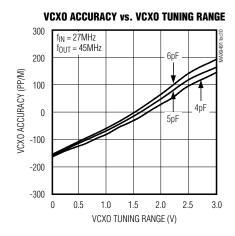


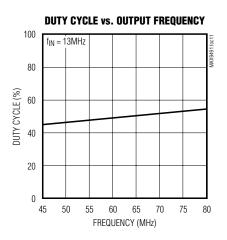




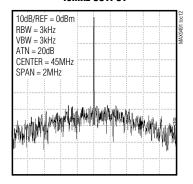
Typical Operating Characteristics (continued)

(VDD = VDDA = +3.3V, TA = +25°C, fIN = 13MHz clock, CL = 10pF, 27MHz, unless otherwise noted.)

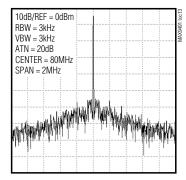




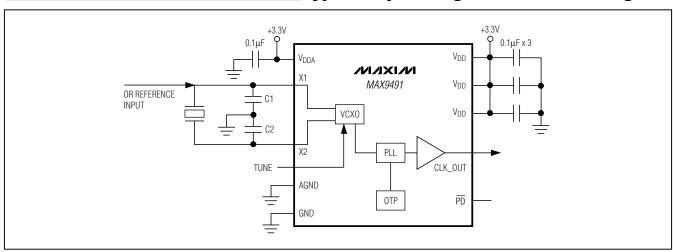
45MHz OUTPUT



80MHz OUTPUT



Typical Operating Circuit/Block Diagram



Pin Description

PIN		NAME	FUNCTION					
TQFN	TSSOP	NAME	FUNCTION					
1	5	TUNE	VCXO Tune Voltage Input. If using a reference clock input or VCXO is not used, connect TUNE to V _{DD} .					
2	_	V _{DDA}	Analog Power Supply. Bypass to GND with a 0.1µF capacitor.					
3	3 — AGND		Analog Ground					
4, 10, 11	6, 9, 11	GND	Ground					
5	7	CLK_OUT	Output Clock. Internally pulled down.					
6–9, 14, 19, 20	2, 3, 8, 10	I.C.	Internally Connected. Leave unconnected for normal operation.					
12, 13, 16	4, 12	V_{DD}	Power Supply. Bypass to GND with a 0.1µF capacitor.					
15 13		PD	Active-Low Power-Down Input. Pull high for normal operation. Drive PD low to place MAX9491 in power-down mode. Internally pulled down.					
17	14	X2	Crystal Connection 2. Leave unconnected if using a reference clock.					
18	1	X1	Crystal Connection 1 or Reference Clock Input					
EP —		EP	Exposed Paddle (TQFN Only). Connect EP to GND or leave unconnected.					

Detailed Description

The MAX9491 features a programmable fractional-N PLL, so frequencies between 4MHz to 200MHz can be generated. The device provides a buffered PLL clock output. The crystal input frequency can be between 5MHz and 35MHz, and the clock input between 5MHz and 50MHz. The internal VCXO has a fine-tuning range of ±200ppm.

Power-Down

Driving PD low places the MAX9491 in power-down mode. PD then sets CLK_OUT to high impedance and

shuts down the PLL. CLK_OUT has an $80\text{k}\Omega$ (typ) internal pulldown resistor.

Voltage-Controlled Crystal Oscillator (VCXO)

The MAX9491's internal VCXO produces a reference clock for the PLL used to generate the CLK_OUT. The oscillator uses a crystal as the base frequency reference and has a voltage-controlled tuning input for micro adjustment in a ±200ppm range. The tuning voltage, V_{TUNE}, can vary from 0 to 3V as shown in Figure 1. The crystal should be AT-cut and oscillate on its fundamental mode with ±30ppm. The crystal shunt capacitor

6 ______ /N/XI/M

should be less than 10pF, including board parasitic capacitance. To achieve up to ±200ppm pullability, make sure the crystal-loading capacitance is less than 14pF. The VCXO is a free-running oscillator. It starts oscillating

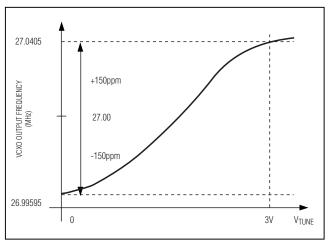


Figure 1. VCXO Tuning Range for a 27MHz Crystal

with an internal POR signal and can be disabled by \overline{PD} . When VCXO is not used, connect TUNE to V_{DD} .

_Applications Information

Using an Input Clock as the Reference

When an input clock is used as the reference, connect the input clock to X1, leave X2 unconnected, and connect TUNE to V_{DD} .

Crystal Selection

When using a crystal with the MAX9491's internal oscillator, connect the crystal to X1 and X2. Choose an ATcut crystal that oscillates on its fundamental mode with ±30ppm and loading capacitance less than 14pF. To achieve a wide VCXO tuning range, select a crystal with motional capacitance greater than 7fF and connect 6pF or less shunt capacitors at both X1 and X2 to ground. When the VCXO is used as an oscillator, select both shunt capacitors to approximately 13pF. The optimal shunt capacitors for achieving minimum frequency offset can be determined experimentally.

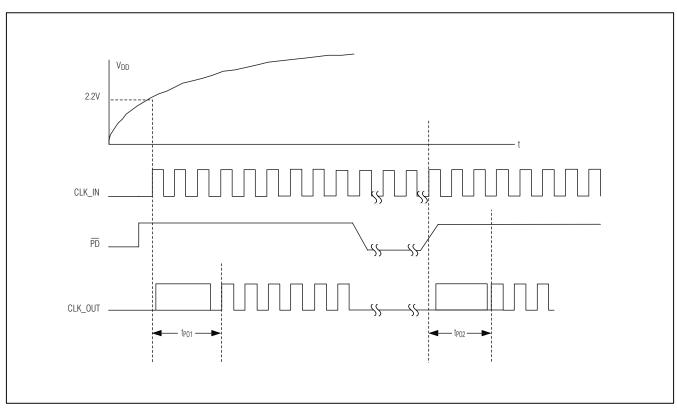


Figure 2. PLL Settling Time

Board Layout Considerations and Bypassing

The MAX9491's high-frequency oscillator requires proper layout to ensure stability. For best performance, place components as close as possible to the device.

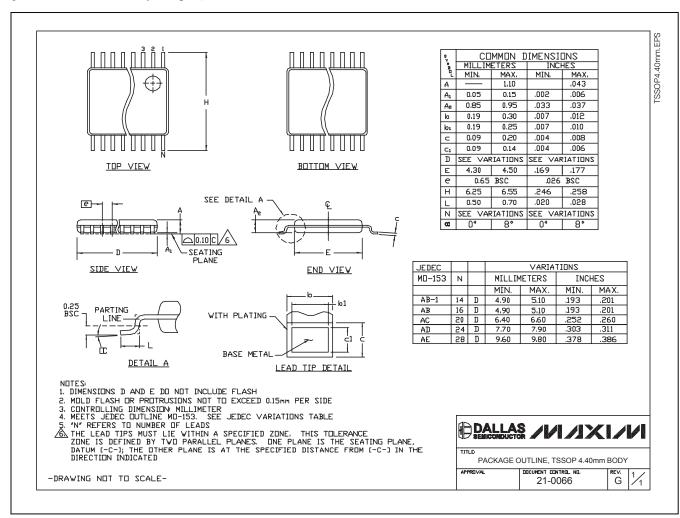
Digital or AC transient signals on GND can create noise at the clock output. Return GND to the highest quality ground available. Bypass each VDD and VDDA with a 0.1µF capacitor, placed as close as possible to the device. Careful PC board ground layout minimizes crosstalk between the output and digital inputs.

Chip	Info	orm	ation

PROCESS: CMOS

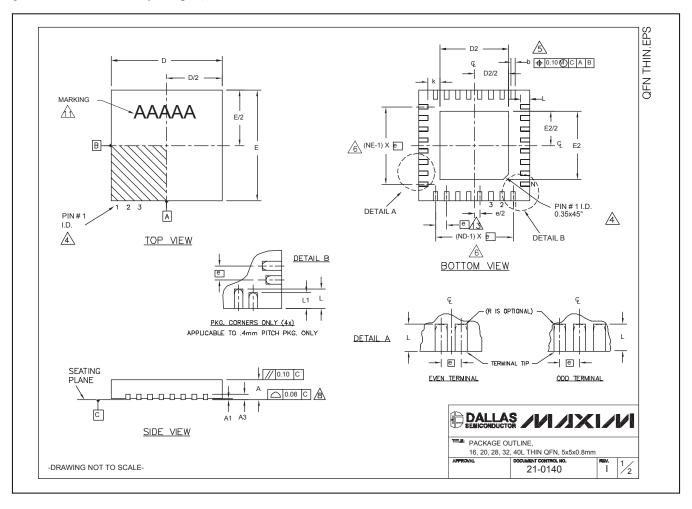
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

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Package Information (continued)

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COMMON DIMENSIONS																
PKG.	1	6L 5x	5	20L 5x5			28L 5x5			32L 5x5			40L 5x5			
SYMBOL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	
A3	0.20 REF.		F.	0.	20 RE	F.	0.	0.20 REF.			0.20 REF.			0.20 REF.		
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.20	0.25	0.30	0.15	0.20	0.25	
D	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	
Е	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	
е	0	.80 B	SC.	0.65 BSC.		0.50 BSC.		0	.50 B	SC.	0.40 BSC.					
k	0.25	-	-	0.25	-	-	0.25	-	-	0.25	-	-	0.25	0.35	0.45	
L	0.30	0.40	0.50	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50	0.40	0.50	0.60	
L1	-	-	-	-	-	-	-	-	-	-	-	-	0.30	0.40	0.50	
N		16		20			28		32			40				
ND		4			5			7		8		10				
NE		4			5			7		8			10			
JEDEC	WHHB			WHH	0	WHHD-1			WHHD-2							

NOTES:

- 1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
- 3. N IS THE TOTAL NUMBER OF TERMINALS.
- THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
- ⚠ DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
- M ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
- 7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- 9. DRAWING CONFORMS TO JEDEC MO220, EXCEPT EXPOSED PAD DIMENSION FOR T2855-3 AND T2855-6.
- WARPAGE SHALL NOT EXCEED 0.10 mm.
- 11. MARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.
- 12 NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY
- LEAD CENTERLINES TO BE AT TRUE POSITION AS DEFINED BY BASIC DIMENSION "e", ±0.05.

-DRAWING NOT TO SCALE-

	EXPOSED PAD VARIATIONS											
PKG.		D2			E2		exceptions	DOWN				
CODES	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	±0.15	ALLOWED				
T1655-2	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T1655-3	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T1655N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T2055-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T2055-4	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T2055-5	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES				
T2855-3	3.15	3.25	3.35	3.15	3.25	3.35	**	YES				
T2855-4	2.60	2.70	2.80	2.60	2.70	2.80	**	YES				
T2855-5	2.60	2.70	2.80	2.60	2.70	2.80	**	NO				
T2855-6	3.15	3.25	3.35	3.15	3.25	3.35	**	NO				
T2855-7	2.60	2.70	2.80	2.60	2.70	2.80	**	YES				
T2855-8	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES				
T2855N-1	3.15	3.25	3.35	3.15	3.25	3.35	**	NO				
T3255-3	3.00	3.10	3.20	3 .00	3.10	3.20	**	YES				
T3255-4	3.00	3.10	3.20	3 .00	3.10	3.20	**	NO				
T3255-5	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T3255N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T4055-1	3.20	3.30	3.40	3.20	3.30	3.40	**	YES				

**SEE COMMON DIMENSIONS TABLE



PACKAGE OUTLINE,

16, 20, 28, 32, 40L THIN QFN, 5x5x0.8mm

21-0140

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.